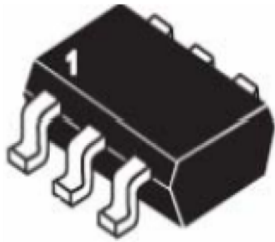
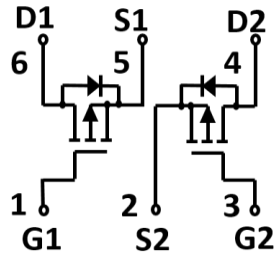
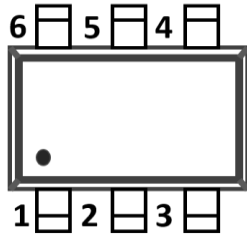


P-Channel Enhancement Mode Field Effect Transistor



SOT-23-6L



Product Summary

- V_{DS} -20V
- I_D -3.7A
- $R_{DS(ON)}$ (at $V_{GS}=-4.5V$) <64 mohm
- $R_{DS(ON)}$ (at $V_{GS}=-2.5V$) <80 mohm
- $R_{DS(ON)}$ (at $V_{GS}=-1.8V$) <95 mohm

General Description

- Trench Power LV MOSFET technology
- Low $R_{DS(ON)}$
- Low Gate Charge

Applications

- Video monitor
- Power management

■ Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Maximum	Unit
Drain-source Voltage	V_{DS}	-20	V
Gate-source Voltage	V_{GS}	± 10	V
Drain Current	I_D	$T_A=25^\circ C$ @ Steady State	-3.7
		$T_A=70^\circ C$ @ Steady State	-3
Pulsed Drain Current ^A	I_{DM}	-16	A
Total Power Dissipation @ $T_A=25^\circ C$	P_D	1.3	W
Thermal Resistance Junction-to-Ambient @ Steady State	$R_{\theta JA}$	96	$^\circ C/W$
Junction and Storage Temperature Range	T_J, T_{STG}	-55~+150	$^\circ C$

■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJS2301A	F2	.S1	3000	/	180000	7" reel



YJS2301A

■ Electrical Characteristics ($T_J=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-250\mu A$	-20			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-20V, V_{GS}=0V, T_C=25^\circ\text{C}$			-1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS}=\pm 10V, V_{DS}=0V$			± 100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-0.4	-0.62	-1.0	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=-4.5V, I_D=-3.4A$		49	64	m Ω
		$V_{GS}=-2.5V, I_D=-3A$		59	80	
		$V_{GS}=-1.8V, I_D=-2.5A$		79	95	
Diode Forward Voltage	V_{SD}	$I_S=-3.7A, V_{GS}=0V$		-0.8	-1.2	V
Maximum Body-Diode Continuous Current	I_S				-3.7	A
Dynamic Parameters						
Input Capacitance	C_{iss}	$V_{DS}=-10V, V_{GS}=0V, f=1\text{MHZ}$		478		pF
Output Capacitance	C_{oss}			81		
Reverse Transfer Capacitance	C_{rss}			51		
Switching Parameters						
Total Gate Charge	Q_g	$V_{GS}=-4.5V, V_{DS}=-10V, I_D=-3.7A$		4.3		nC
Gate Source Charge	Q_{gs}			0.8		
Gate Drain Charge	Q_{gd}			1.1		
Turn-on Delay Time	$t_{D(on)}$	$V_{GS}=-4.5V, V_{DD}=-10V, I_D=-1A, R_{GEN}=2.5\Omega$		12		ns
Turn-on Rise Time	t_r			54		
Turn-off Delay Time	$t_{D(off)}$			15		
Turn-off Fall Time	t_f			9		

A.Pulse Test: Pulse Width $\leq 300\mu s$, Duty cycle $\leq 2\%$.

■ Typical Performance Characteristics

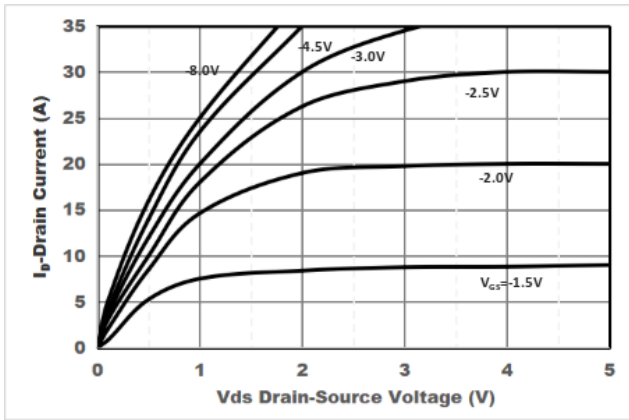


Figure1. Output Characteristics

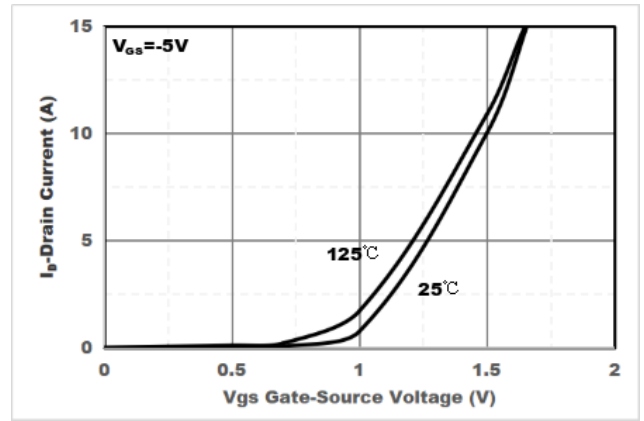


Figure2. Transfer Characteristics

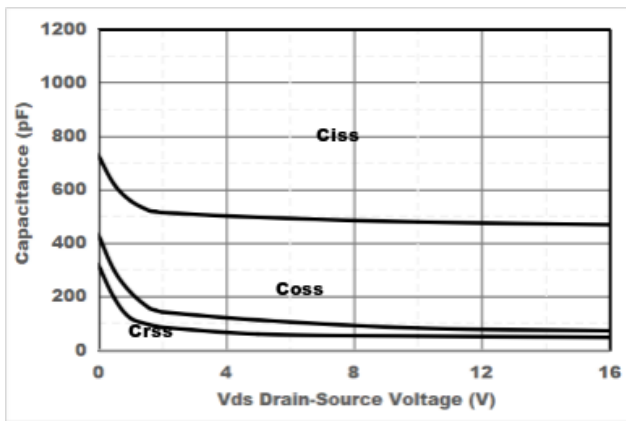


Figure3. Capacitance Characteristics

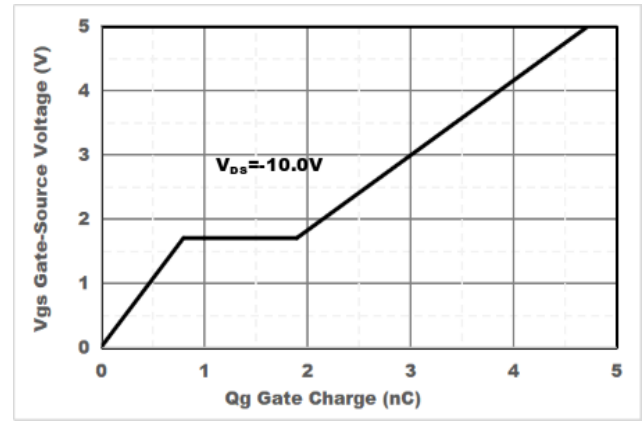


Figure4. Gate Charge

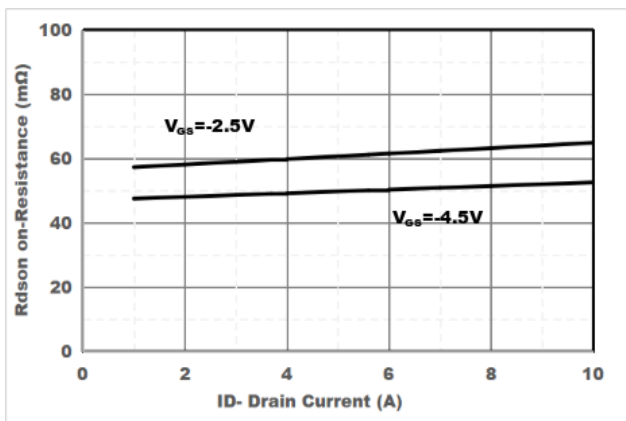


Figure5. Drain-Source on Resistance

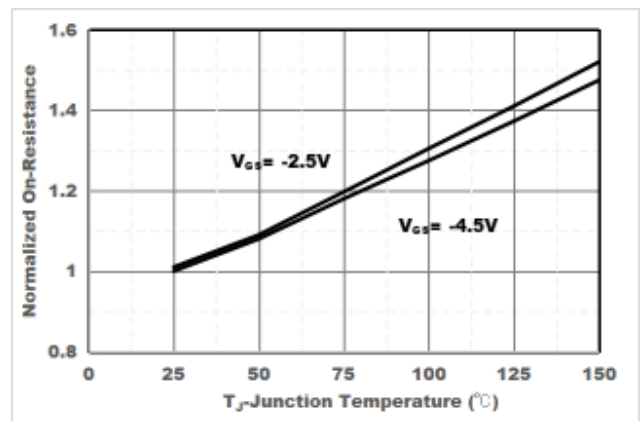


Figure6. Drain-Source on Resistance

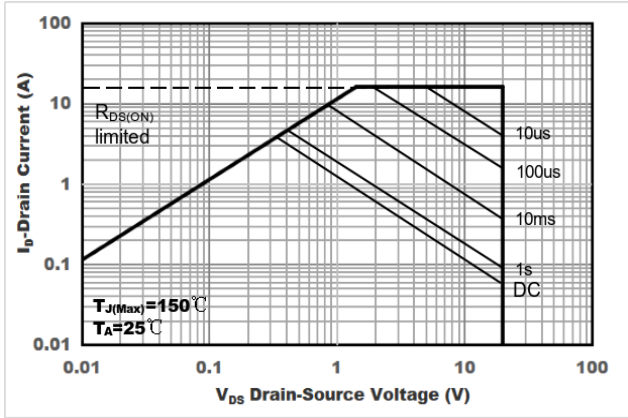


Figure7. Safe Operation Area

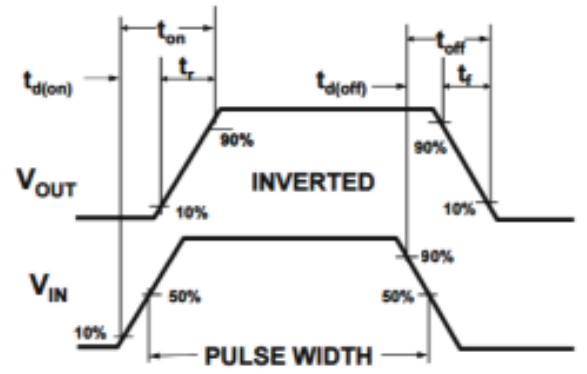
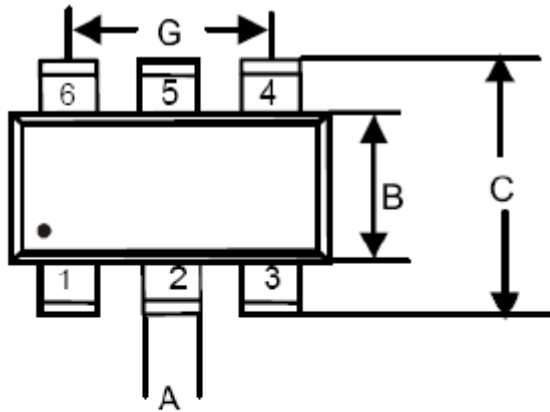


Figure8. Switching wave

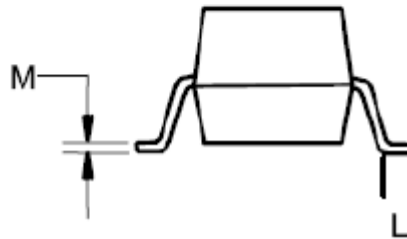
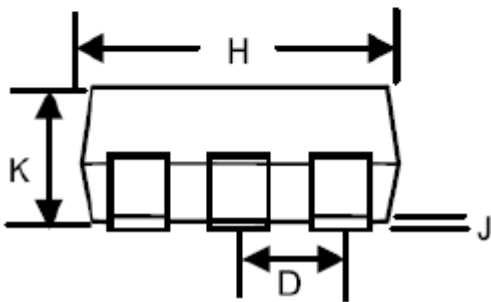


YJS2301A

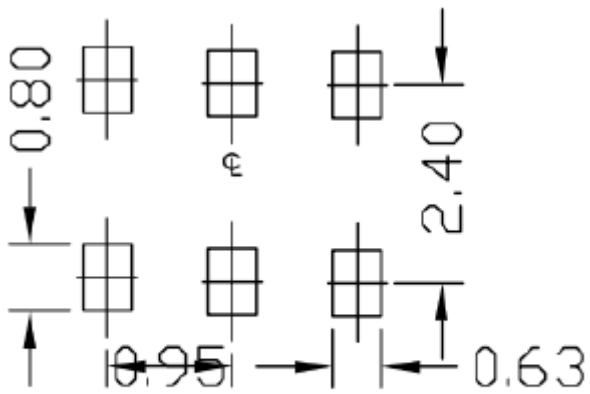
■ SOT-23-6L Package information



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.012	.020	0.30	0.50	
B	.051	.070	1.30	1.80	
C	.087	.126	2.20	3.20	
D	.037		0.95BSC		
G	.074		1.90BSC		
H	.106	.122	2.70	3.10	
J	.002	.006	0.05	0.15	
K	.035	.051	0.90	1.30	
L	.012	.024	0.30	0.60	
M	.003	.008	0.08	0.22	



■ SOT-23-6L Suggested Pad Layout



UNIT: mm



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